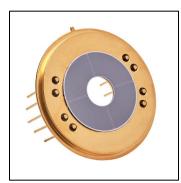


Quad Electron Detector 146 mm²



FEATURES

- Ideal for Electron Detection
- Circular Active Area

Electro-Optical Characteristics at 25°C (Per Element)

Parameters	Test Conditions	Min	Тур	Max	Units
Active Area (per element)			36.5		mm²
Responsivity	(see graphs on next page)	0.07	0.08	0.09	A/W
Shunt Resistance, RsH	V _R = ± 10 mV	10			MOhm
Capacitance, C	V _R = 0 V		2	6	nF
Rise Time	$V_R = 2 V, R_L = 50 \Omega$			2	usec

Thermal Parameters

Storage and Operating Temperature Range	Units
Ambient ¹	-10°C to 40°C
Nitrogen or Vacuum	-20°C to 80°C
Lead Soldering Temperature ²	260°C

¹ Temperatures exceeding these parameters may create oxide growth on the active area.

Over time responsivity to low energy radiation and wavelengths below 150 nm will be compromised.

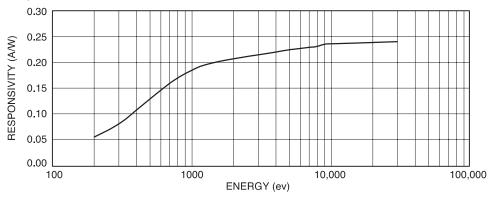
Shipped with temporary cover to protect photodiode and wire bond. Review Opto Diode, "Handling Precautions for IRD Detectors", prior to removing cover.

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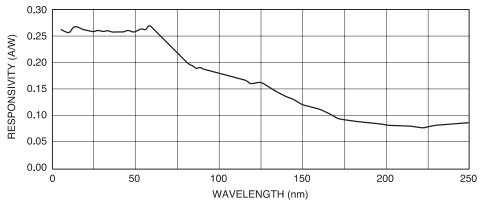
 $^{^2\,0.080&}quot;$ from case for 10 seconds.



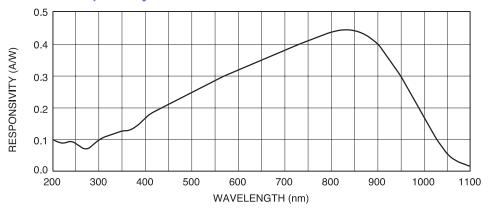
Typical Electron Response



Typical EUV-UV Photon Response



Typical UV-VIS-NIR Photon Responsivity

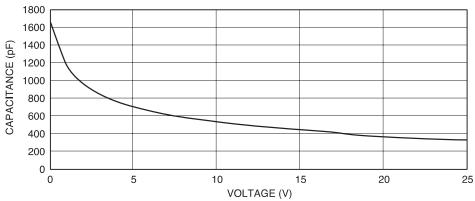


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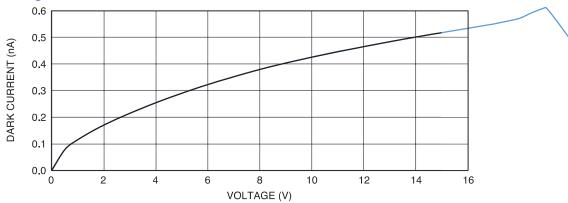


Quad Electron Detector 146 mm²

Capacitance vs. Voltage



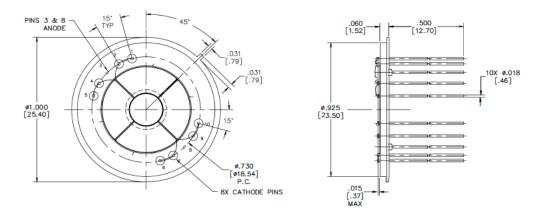
Dark Current vs. Voltage

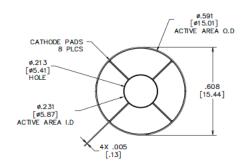


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Package Information





Dimensions are in inch [metric] units.

Specifications are subject to change without prior notice.

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